

2SK2333

(F6F70HVX2)

700V 6A

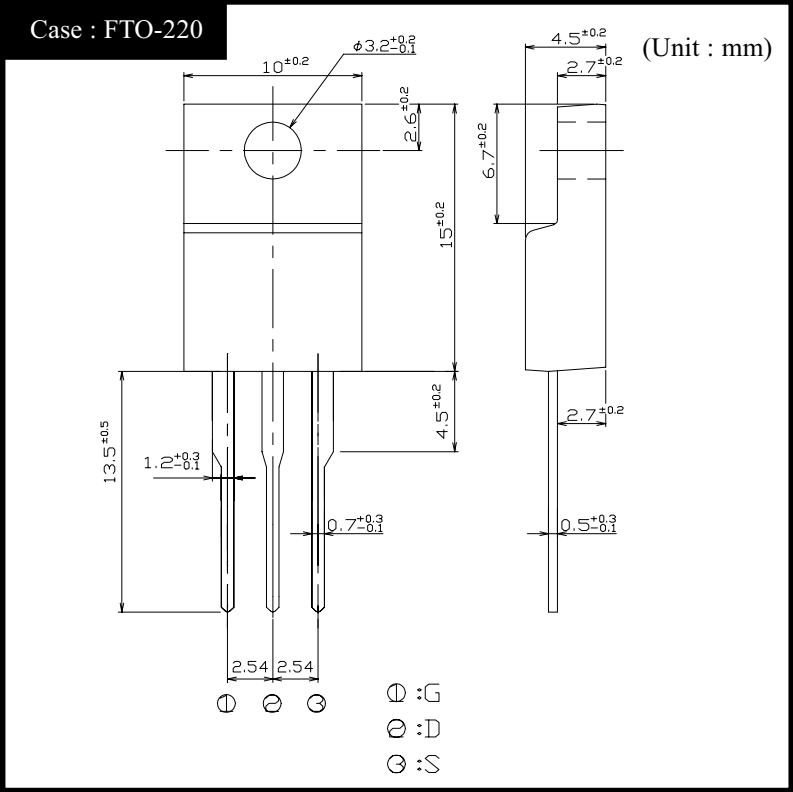
FEATURES

- Input capacitance (Ciss) is small.
Especially, input capacitance at 0 bias is small.
- The static Rds(on) is small.
- The switching time is fast.
- Avalanche resistance guaranteed.

APPLICATION

- Switching power supply of AC 240V input
- High voltage power supply
- Inverter

OUTLINE DIMENSIONS



RATINGS

●Absolute Maximum Ratings (Tc = 25°C)

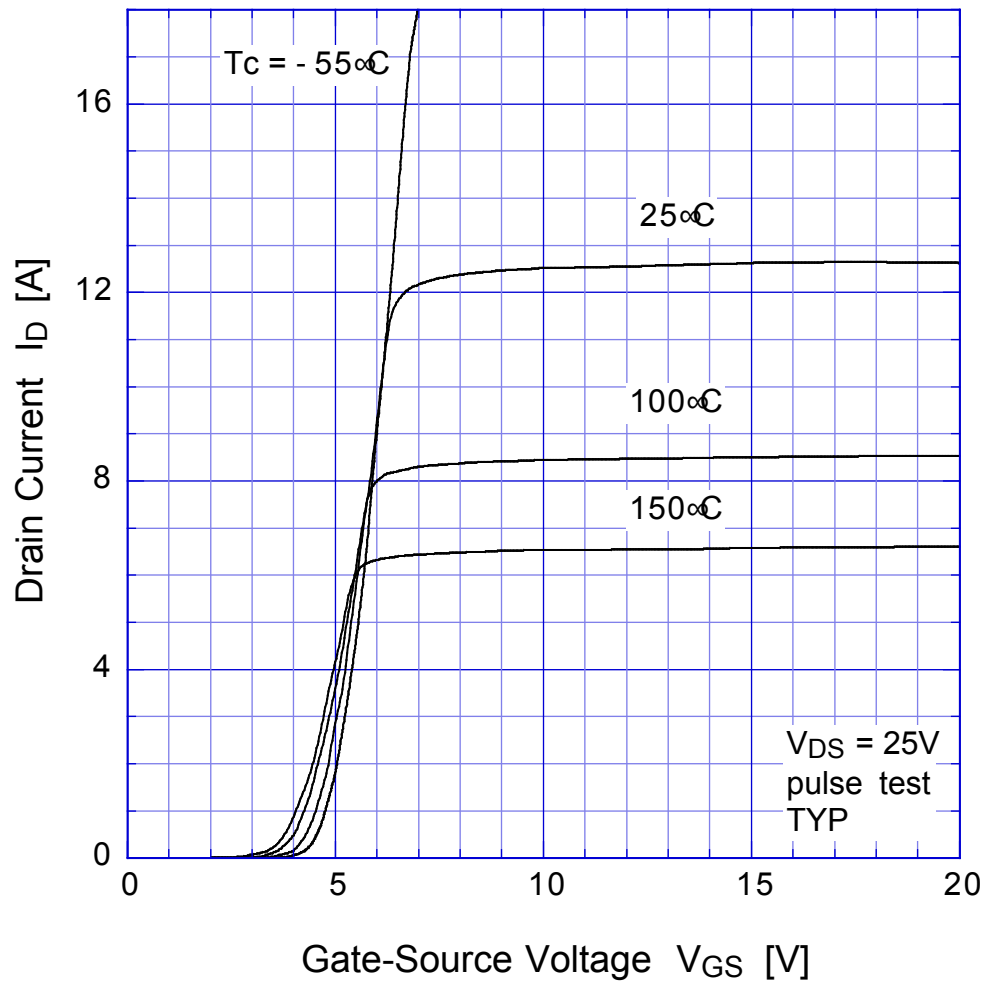
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-55~150	°C
Channel Temperature	T _{ch}		150	
Drain-Source Voltage	V _{DSS}		700	V
Gate-Source Voltage	V _{GSS}		±30	
Continuous Drain Current (DC)	I _D		6	A
Continuous Drain Current (Peak)	I _{DP}	Pulse width ≤ 10 μs, Duty cycle ≤ 1/100	18	
Continuous Source Current (DC)	I _S		6	
Total Power Dissipation	P _T		50	W
Repetitive Avalanche Current	I _{AR}	T _{ch} = 150°C	6	A
Single Avalanche Energy	E _{AS}	T _{ch} = 25°C	190	
Repetitive Avalanche Energy	E _{AR}	T _{ch} = 25°C	19	
Dielectric Strength	V _{dis}	Terminals to case, AC 1 minute	2	kV
Mounting Torque	TOR	(Recommended torque : 0.3 N·m)	0.5	N·m

●Electrical Characteristics $T_c = 25^{\circ}\text{C}$

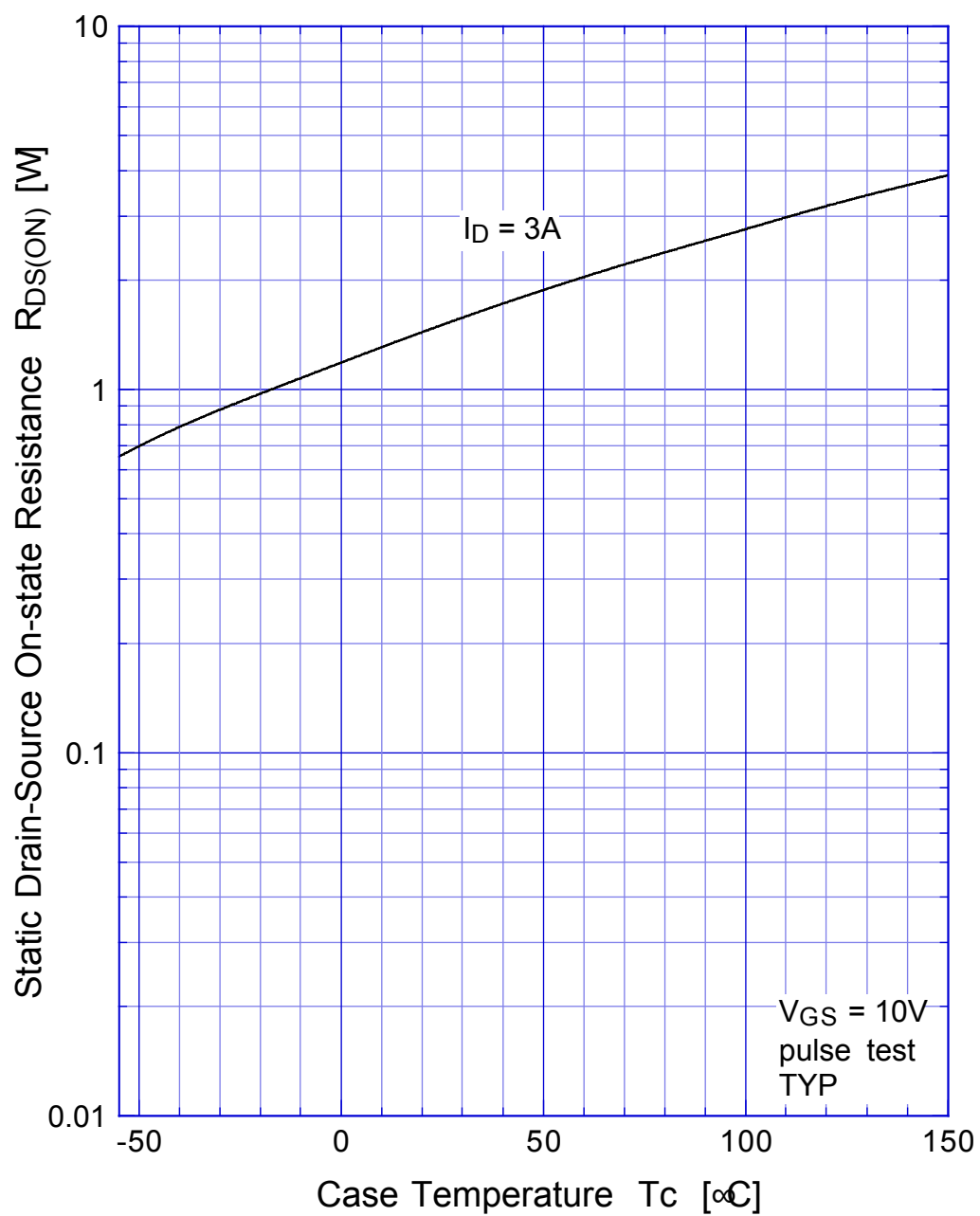
Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 1\text{mA}$, $V_{GS} = 0\text{V}$	700			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 700\text{V}$, $V_{GS} = 0\text{V}$			250	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 30\text{V}$, $V_{DS} = 0\text{V}$			± 0.1	
Forward Transconductance	g_{fs}	$I_D = 3\text{A}$, $V_{DS} = 10\text{V}$	3.0	5.0		S
Static Drain-Source On-state Resistance	$R_{DS(ON)}$	$I_D = 3\text{A}$, $V_{GS} = 10\text{V}$		1.5	2.0	Ω
Gate Threshold Voltage	V_{TH}	$I_D = 1\text{mA}$, $V_{DS} = 10\text{V}$	2.5	3.0	3.5	V
Source-Drain Diode Forward Voltage	V_{SD}	$I_S = 3\text{A}$, $V_{GS} = 0\text{V}$			1.5	
Thermal Resistance	θ_{jc}	junction to case			2.5	$^{\circ}\text{C}/\text{W}$
Total Gate Charge	Q_g	$V_{DD} = 400\text{V}$, $V_{GS} = 10\text{V}$, $I_D = 6\text{A}$		35		nC
Input Capacitance	C_{iss}	$V_{DS} = 10\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$		1250		pF
Reverse Transfer Capacitance	C_{rss}			250		
Output Capacitance	C_{oss}			530		
Turn-On Time	t_{on}	$I_D = 3\text{A}$, $R_L = 50\Omega$, $V_{GS} = 10\text{V}$		60	110	ns
Turn-Off Time	t_{off}			160	250	

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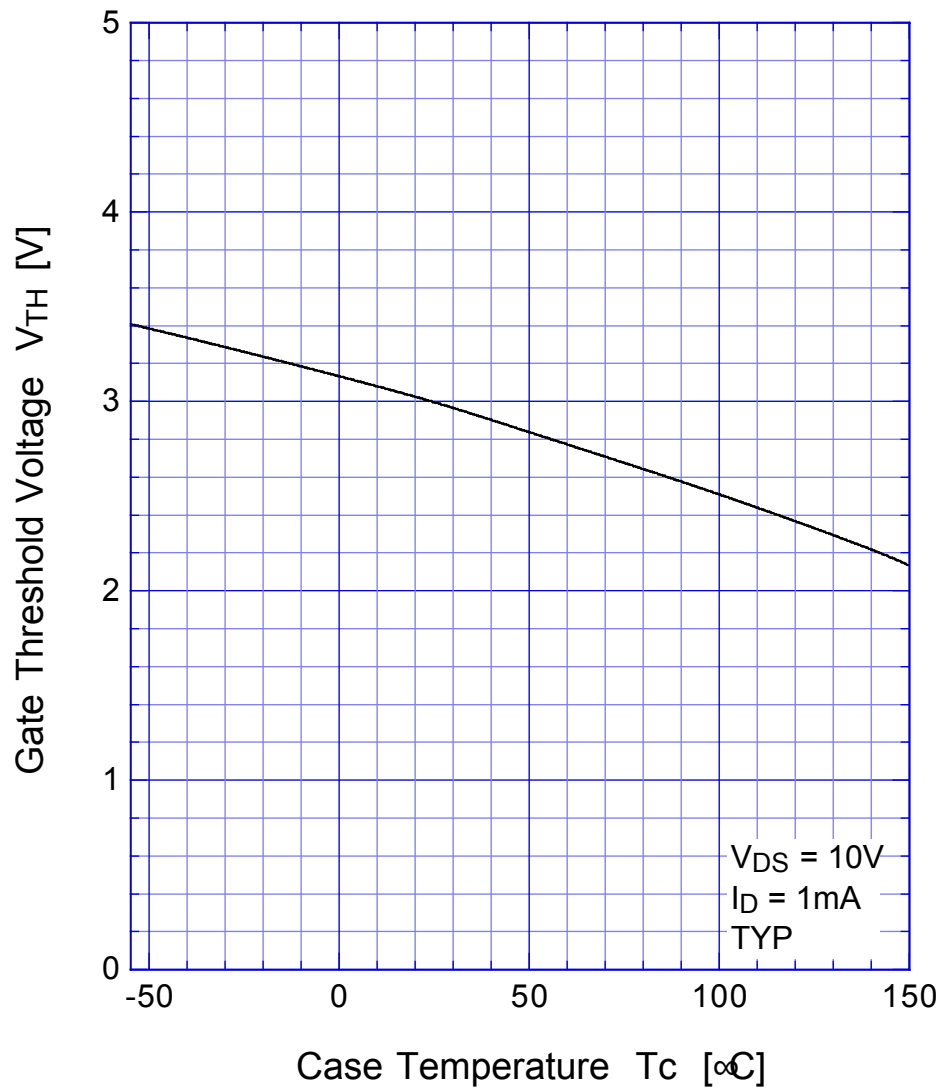
Transfer Characteristics



2SK2333 Static Drain-Source On-state Resistance

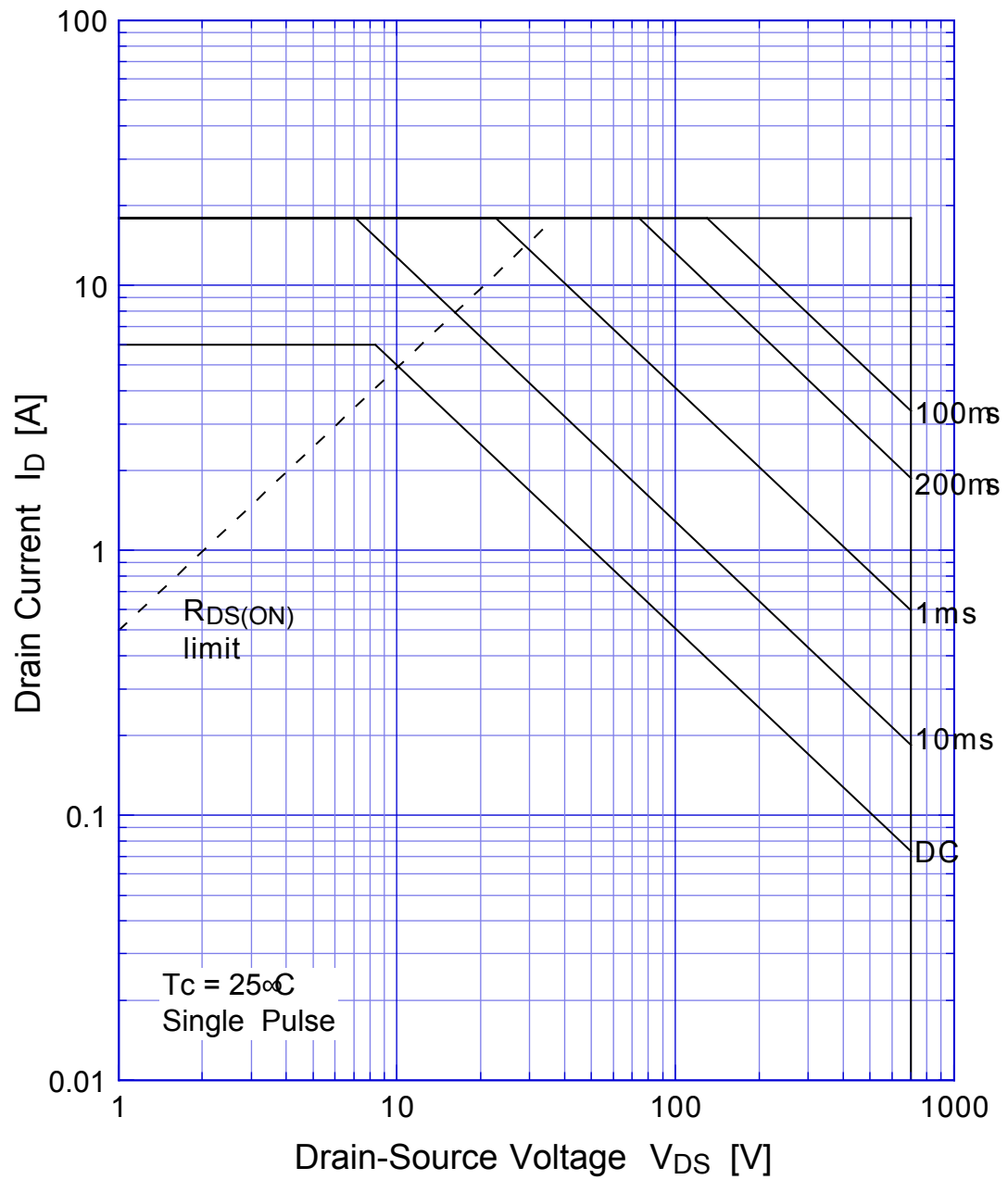


2SK2333 Gate Threshold Voltage

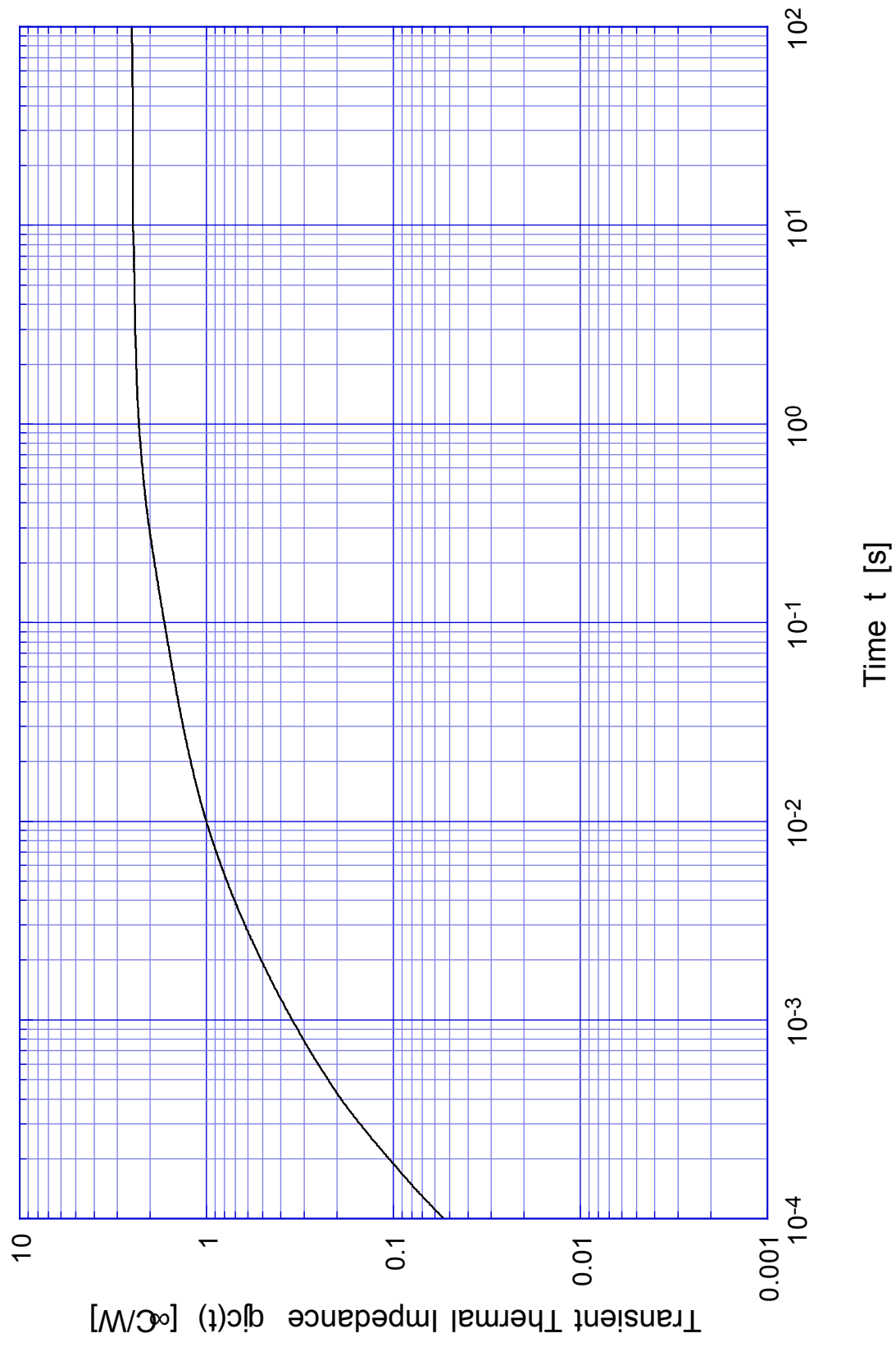


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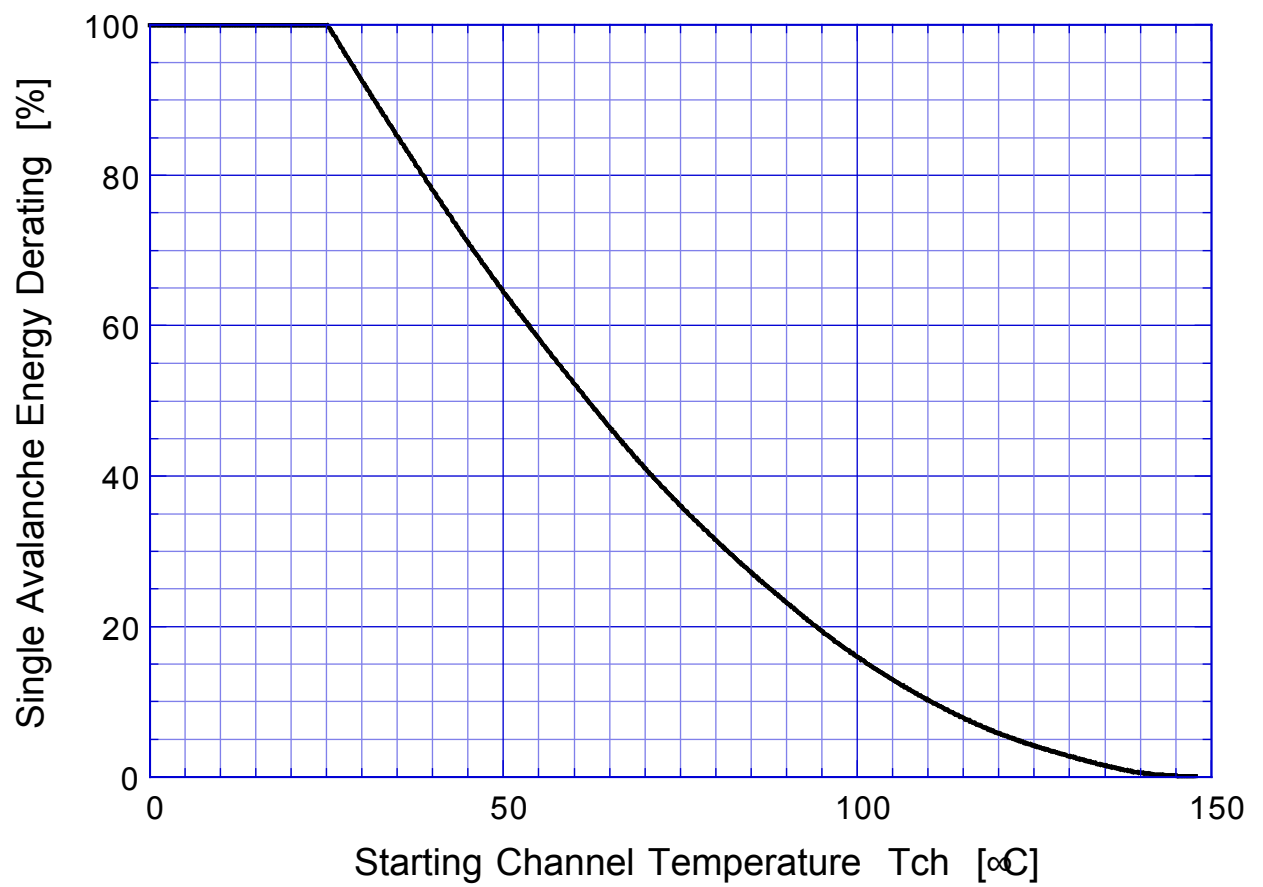
Safe Operating Area



2SK2333 Transient Thermal Impedance

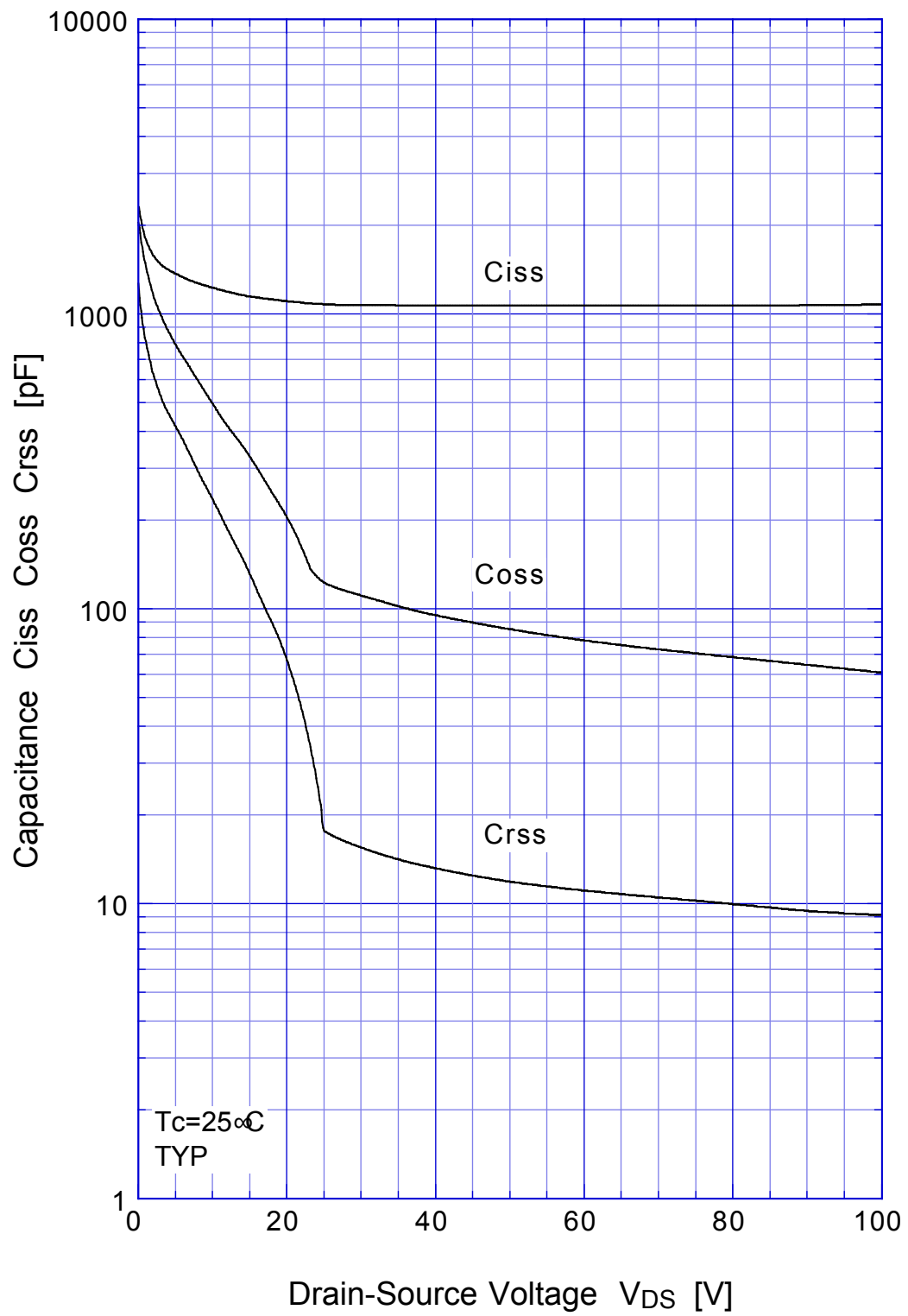


2SK2333 Single Avalanche Energy Derating

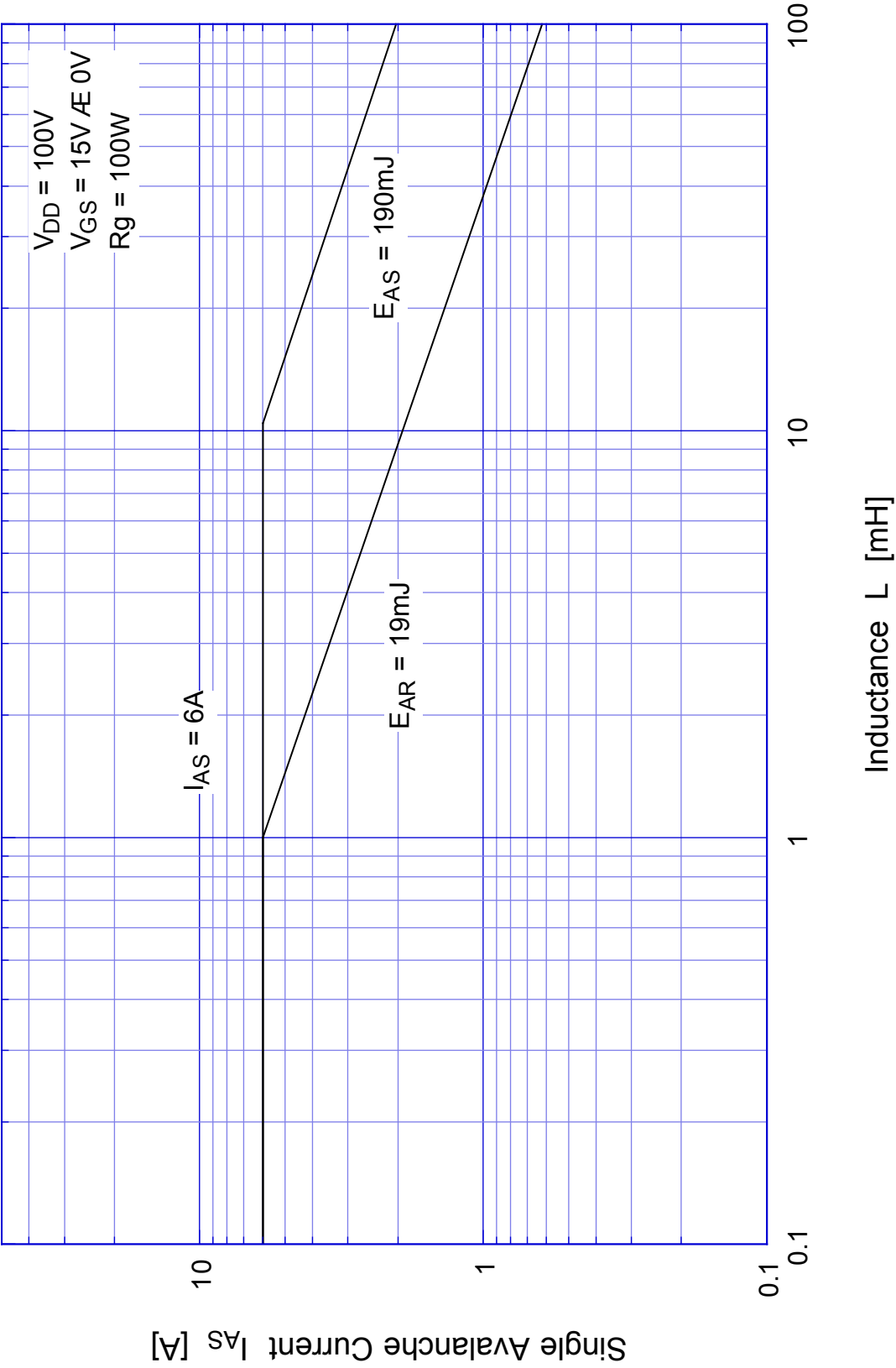


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Capacitance

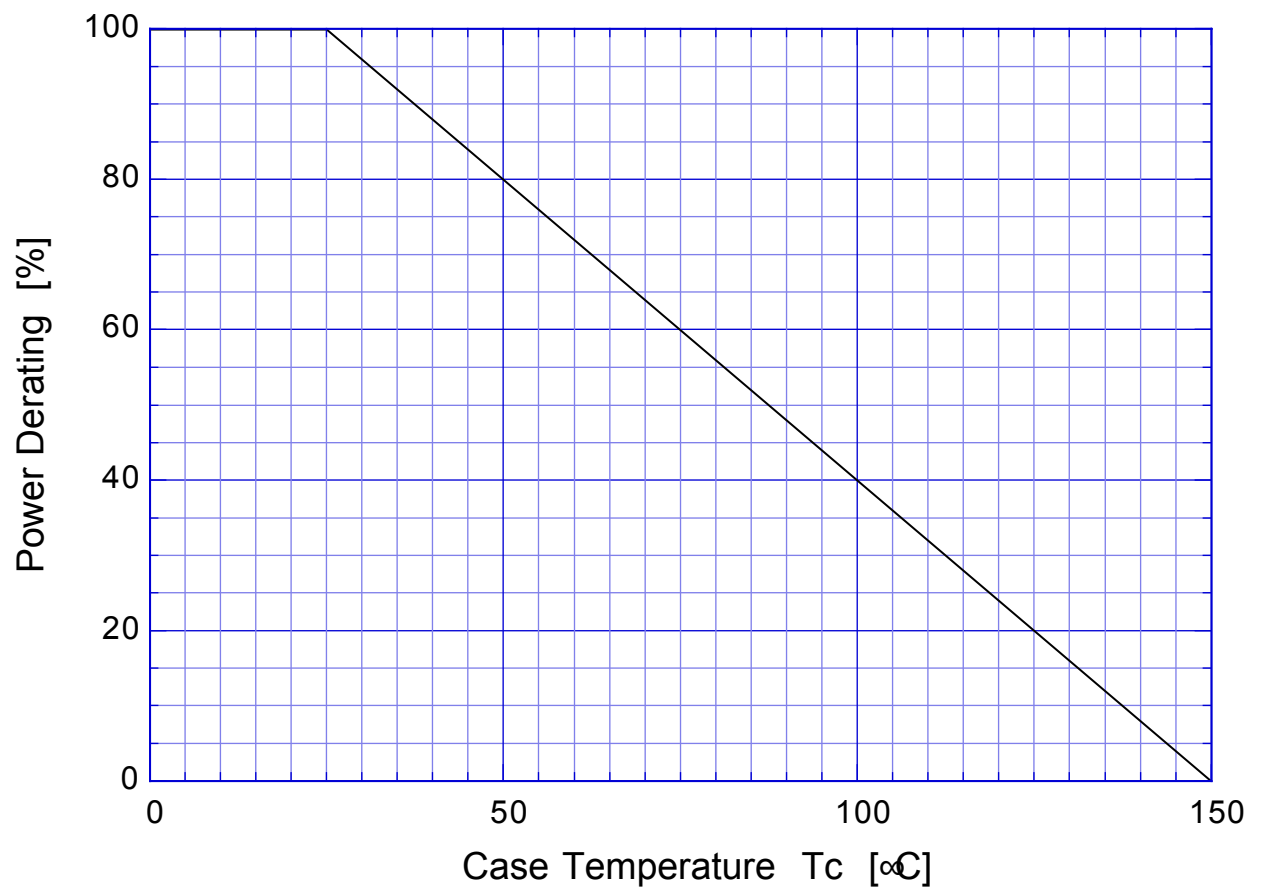


2SK2333 Single Avalanche Current - Inductive Load



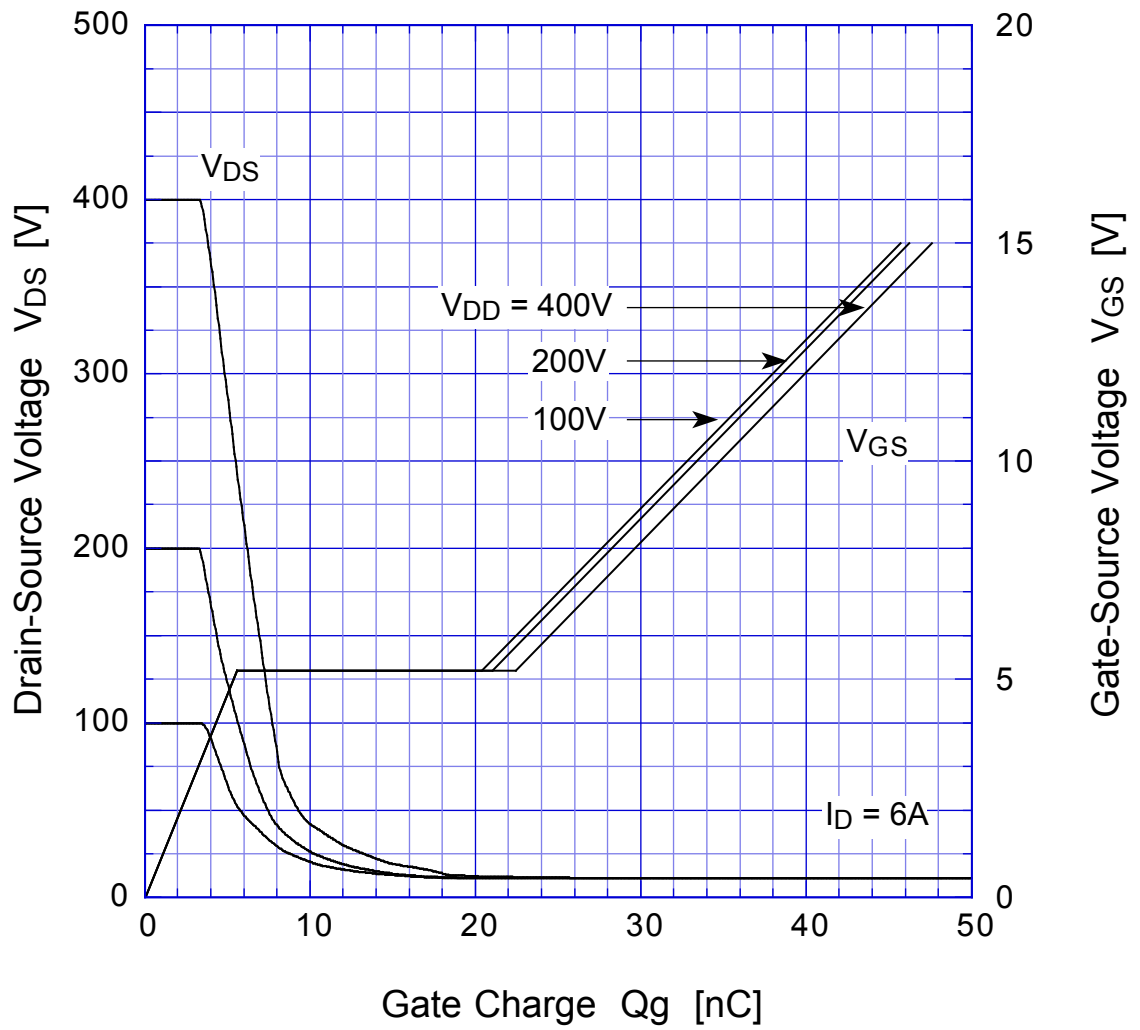
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Power Derating



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Gate Charge Characteristics



This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.